





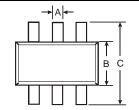
DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

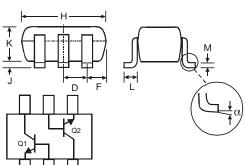
Features

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device, Note 4 and 5

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Copper leadframe).
- Marking Information: K3M, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.008 grams (approximate)





SOT-26									
Dim	Min	Max	Тур						
Α	0.35	0.50	0.38						
В	1.50	1.70	1.60						
C	2.70	3.00	2.80						
D			0.95						
F	_	_	0.55						
H	2.90	3.10	3.00						
J	0.013	0.10	0.05						
K	1.00	1.30	1.10						
L	0.35	0.55	0.40						
М	0.10	0.20	0.15						
α 0° 8° —									
All Dimensions in mm									

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	300	V
Collector-Emitter Voltage	V _{CEO}	300	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current (Note 1) (Note 2)	I _C	500	mA
Power Dissipation (Note 1)	P _d	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ hetaJA}$	417	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. When operated under collector-emitter saturation conditions within the safe operating area defined by the thermal resistance rating (R_{0JA}), power dissipation rating (P_d) and power derating curve (Figure 1).
- No purposefully added lead.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 6)							
Collector-Base Breakdown Voltage	V _{(BR)CBO}	300	_	V	$I_C = 100 \mu A, I_E = 0$		
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	300	_	V	$I_C = 1.0 \text{mA}, I_B = 0$		
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6.0	_	V	$I_E = 100 \mu A, I_C = 0$		
Collector Cutoff Current	I _{CBO}		100	nA	$V_{CB} = 200V, I_{E} = 0$		
Collector Cutoff Current	I _{EBO}		100	nA	$V_{CE} = 6.0V, I_{C} = 0$		
ON CHARACTERISTICS (Note 6)							
	h _{FE}	25	_	_	$I_C = 1.0 \text{mA}, V_{CE} = 10 \text{V}$		
DC Current Gain		40			$I_C = 10mA, V_{CE} = 10V$		
		40			$I_C = 30mA$, $V_{CE} = 10V$		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.5	V	$I_C = 20 \text{mA}, I_B = 2.0 \text{mA}$		
Base-Emitter Saturation Voltage	V _{BE(SAT)}		0.9	V	$I_C = 20mA$, $I_B = 2.0mA$		
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance	C_cb		3.0	pF	$V_{CB} = 20V, f = 1.0MHz, I_{E} = 0$		
Current Gain-Bandwidth Product	f⊤	50		MHz	$V_{CE} = 20V, I_{C} = 10mA,$ f = 100MHz		

Notes: 6. Short duration pulse test used to minimize self-heating effect.

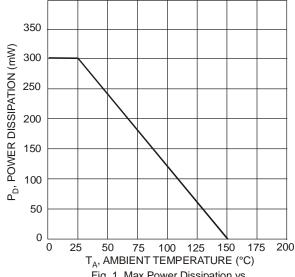
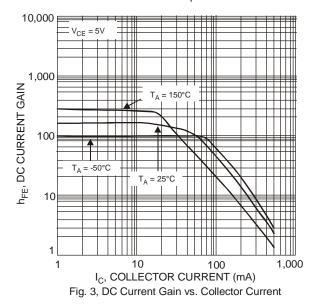


Fig. 1, Max Power Dissipation vs. **Ambient Temperature**



2.0 V_{CE(SAT)}, COLLECTOR TO EMITTER SATURATION VOLTAGE (V) 1.6 1.4 1.2 1.0 8.0 0.6 0.4 0.2 10 1,000 100 I_C, COLLECTOR CURRENT (mA)

Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

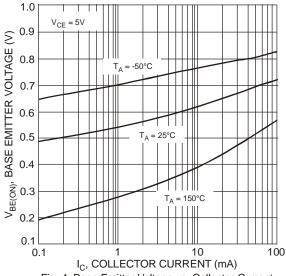
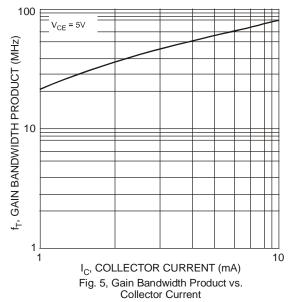


Fig. 4, Base Emitter Voltage vs. Collector Current



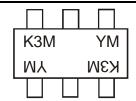


Ordering Information (Note 5 & 7)

Device	Packaging	Shipping			
MMDTA42-7-F	SOT-26	3000/Tape & Reel			

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K3M = Product Type Marking Code

YM = Date Code Marking

Y = Year ex: P = 2003

M = Month ex: 9 = September

Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	R	S	Т	U	V	W	Х	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))